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SCM1101A Highly integrated PWM controller

Features

- Soft-Start Function, Externally Programmable
- Extremely Low Start-up current of 1uA typical
- Frequency Reduction at Light Load and Burst Mode Control under no load
- Programmable Maximum Switching Frequency, up to 480KHz
- Built-in Slope Compensation and Feed-forward Compensation Circuit
- Cycle-by-Cycle Current Limiting
- RI Pin Short-circuit Protection
- VDD Over-Voltage Protection (OVP) and Under-Voltage Lockout (UVLO)
- Built-in (over-current protection)OCP time
- Feedback Open-loop Protection/Short-circuit Protection
- VIN Under-Voltage Protection

Application

- DC-DC Isolate Power Supplies
- Instrument Power Supplies
- Isolated Telecom Converter

Description



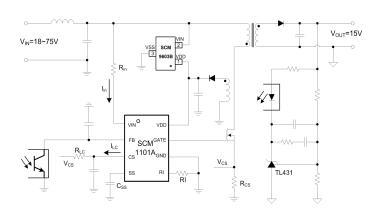
Packaging

Mechanical package: MSOP-8 (see "Ordering information" for details of silk screen).

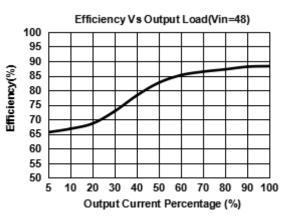
This highly integrated SCM1101A current mode PWM controller is ideal for Isolate DC-DC converter applications. The PWM switching frequency is internally adjusted within a tight range. The chip's maximum working frequency can be changed by means of external resistors. To conserve energy under light load conditions, the green mode function continuously decreases the switching frequency, thus enabling the converter to maintain high efficiency over the entire load range. For optimized standby power consumption, the power supply enters into a burst mode under no load conditions.

The SCM1101A design also integrates a series of protection features that will enhance the power system's reliability. These functions include VIN Under-Voltage Protection, VDD Under-Voltage Lock Out (UVLO), VDD Over-Voltage Protection, Soft-Start pin SS Suspended Protection, Feedback Open-Loop Protection / Short-Circuit and Overload Protection and CS pin Suspended Protection.

Simplified Schematic



Function Curves



NOTE: Vin=18~75V, Vout=15V, Pout=10W.



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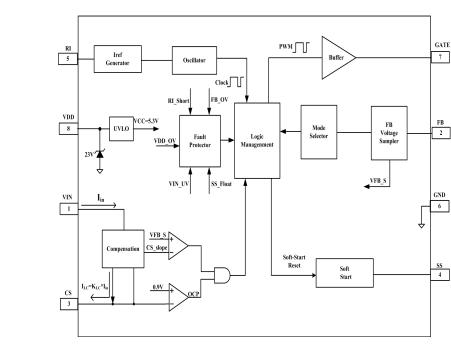
VER.A4 2020.04 Page 1 of 13

Contents

Features and Package	1
Application	1
Description	1
Simplified schemetic and Function Curves	. 1
Pins and Description	2
Absolute Maximum Ratings	3
Recommended Operating Conditions	3
Thermal Resistance Information	3
Electrical Characteristics.	3

Typical Characteristics Curves	5
Parameter Measurement Information	6
Features Description	7
Product Operation Mode	7
Extended Output Design	10
Application Circuit	10
Suggestions of Power Use	.10
Order, Packaging and Packing	.11

Internal Block



Pin Description

Pins

1 VIN[°]

2 FB

3 CS

4 SS

(TOP VIEW)

MSOP8

VDD 8

GATE 7

GND 6

RI 5

Pin No.	Pin Name	I/O	Description
1	VIN	I	Line input voltage sensing, connected to rectified line input source via large value resistor.
2	FB	I	Voltage feedback via opto-coupler for loop regulation. The PWM's duty cycle is generated by the FB voltage and the current sense signal at pin 3 (CS).
3	CS	I	Current sense input.
4	SS	I	Soft-start time setting port. Soft-start time is set by connecting an external capacitor from pin to GND.
5	RI	I	Switching frequency setting with external resistor connected from RI and GND. This pin has short-to-GND protection.
6	GND	Р	IC ground.
7	GATE	0	External power MOSFET gate drive output via totem-pole driver .
8	VDD	Р	IC power supply.

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VER.A4 2020.04 Page 2 of 13

Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
Power Supply Voltage	VDD		23	V
VDD Clamping Current	Iclamp		10	mA
Gate-drive Voltage (at GATE)	V _{DRV}	-0.6	30	
Nellana Danaa	FB,CS,RI	-0.6	6	V
Voltage Range	SS	-0.6	6	1
Storage Temperature Range	Тѕтҫ	-55	150	°.
Lead Temperature, Soldering for 10 seconds	Distance 0.6mm from case,10 sec		260	
Moisture Sensitivity Level	MSL	M	SL3	
	Human Body Model (HBM)		3000	
Electro Static Discharge (ESD)	Charged Device Model (CDM)		1000	

olute Maximum Ratings not recommended, they may severely affect the device reliability and/or result in permanent damage.

Recommended Operating Conditions

VDD=12V and T=25°C, unless otherwise noted.

Parameter	Symbol	Min	Max	Unit
Power Supply Voltage	V _{VDD}	7.5	14	V
VDD Bypass Capacitor	C _{VDD}	0.047	20	uF
Operating Switching Frequency	F	200	480	kHz
Operating Junction Temperature	TJ	-40	125	°C

Thermal Resistance Information

Heating current is 50mA and heating time is 600s; test current is 1mA and test time is 600s.

Parameter		Value	Unit
Junction-to-ambient thermal resistance	θ _{JA}	230	°C/W
The reference standard is JESD51-1.			

Electrical Characteristics

VDD=12V and T=25 $^\circ\!\mathrm{C}$, unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Supply Section(VDD Pin)					
ISTART_UP	VDD Start-up Current	DD Start-up Current Current flow into VDD port measured at VDD=6V		1	40	uA
I _{VDD_OP}	Operating Supply Current	V _{FB} =3V,RI=24k Ohm	1.0	1.4	2	mA
V _{UVLO_ON}	VDD Turn-on Threshold	VDD Voltage increasing	6.4	7.0	7.6	V
VUVLO_OFF	VDD Turn-off Threshold	VDD Voltage decreasing	5.9	6.4	6.9	V
V _{OVP}	VDD OVP Threshold	VDD from 15V~21V	17	18	19	V
V _{OVP_HYS}	VDD OVP Hysteresis			3.2		V
V _{CLAMP}	VDD Clamping Voltage	the absorption current capacity when VDD increased suddenly	20	22.5	25	v
Feedback Input Section	(FB pin)	· · ·				
A _{V_CS}	PWM Input Gain	∆V _{FB} /∆V _{CS}		3.5		V/V
V_{FB}_{OPEN}	FB pin Open Voltage			5.3		V
I _{FB_SHORT}	FB pin Short-circuit Current	Current measured when FB pin connected to GND		1.2		mA
Z _{FB_IN}	FB Input Impedance			4.5		kΩ



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VER.A4 2020.04 Page 3 of 13

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Feedback Input Section (I	-B pin, continued)					
$V_{\text{TH}_{PL}}$	Power Limiting FB Threshold Voltage			4.5		V
Oscillator Section (RI pin)			•			
Fosc	Oscillator Frequency	RI=24K	285	305	325	kHz
$\triangle F_{\text{TEMP}}$	Frequency Temperature Stability	-40℃~125℃		5		%
$\triangle F_{VDD}$	Frequency Voltage Stability	V _{VDD} =7~16V		5		%
D _{MAX}	Maximum Duty Cycle		74	78	82	%
RIRANGE	RI Operating Range		15	24	48	kΩ
V _{RI_OPEN}	RI Pin Open Voltage		1.88	1.98	2.08	V
F _{BM}	Burst Mode Frequency			1/8 Fosc		kHz
Current Sense Input Sect	ion (CS pin)		·			
V _{CST_MAX}	Internal Current Limit Threshold		0.85	0.9	0.95	V
sK _{LC}	Line-Sense Current Ratio	I _{LC} / I _{IN}		5		
Line-sense Voltage Section	on (VIN pin)		•			
R _{VIN}	VIN Input Resistor		36	45	54	kΩ
$V_{\text{UVIN}_\text{OFF}}$	VIN Under-voltage Protection Threshold	R _{IN} =680K,RI=24K	6.2	6.6	7.0	V
Vuvin_on	VIN Under-voltage Protection Turn-off Threshold	R _{IN} =680K,RI=24K	7.1	7.6	8.1	V
Timing Section						
T _{D_OVP}	VDD OVP Delay Time			200		uS
	UVIN Delay Time			200		uS
T _{D_PL}	FB Pin Open-loop Protection Delay Time	RI=24K		32.5		mS
T _{RI_SHORT}	RI Pin Short-circuit Protection Detection Time	RI=24K		52		uS
T _{SLEEP}	Rest Time of FB Pin Open-loop Protection	RI=24K		1.67		S

Switch Characteristics

VDD=12V and T=25°C, unless otherwise noted.

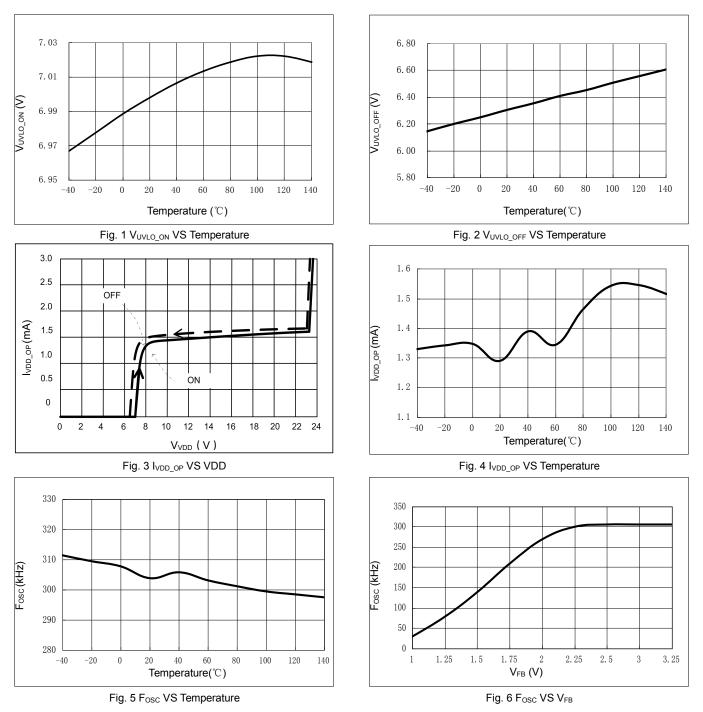
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _{OL}	Output Low Level	I _O =20 mA(sink)		0.1		V
V _{OH}	output High Level	I ₀ =20 mA (source)		11.8		V
T _R	Output rise Time	C _{GATE} =1nF		20		nS
T _F	Output Fall Time	C _{GATE} =1nF		20		nS



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VER.A4 2020.04 Page 4 of 13

(1) Condition: VDD=12V, RI=24kΩ, T=25°C (unless otherwise specified).(2)The curves UVIN (ON) vs Temperature and UVIN (OFF) vs temperature are measured with RI=24kΩ and Rin=680kΩ.



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VER.A4 2020.04 Page 5 of 13

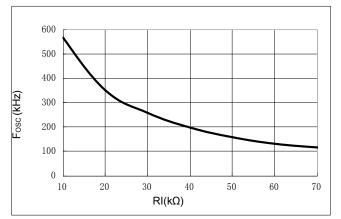


Fig. 7 Fosc VS RI

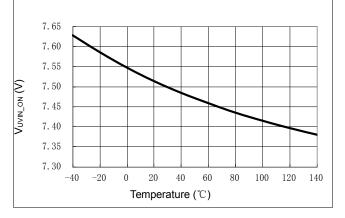


Fig. 9 VUVIN_ON VS Temperature

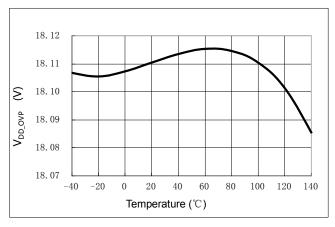


Fig. 11 V_{DD_OVP} VS Temperature

Parameter Measurement Information

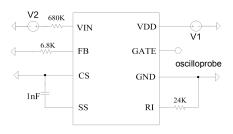
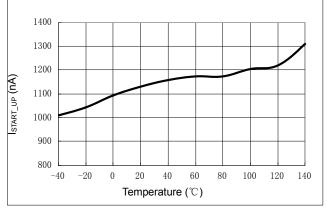


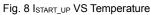
Fig.12 Schematic Diagram of Test Circuit for Switch Characteristics



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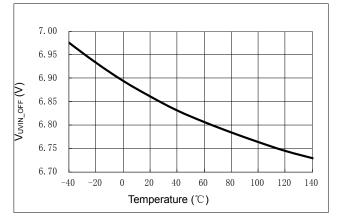
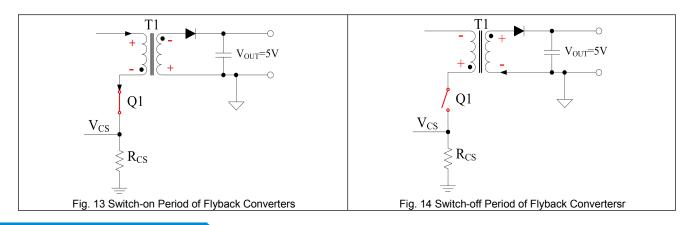


Fig. 10 V_{UVIN_OFF} VS Temperature

Flyback Converters

As shown in Fig. 13 and Fig. 14, when Q1 is " on " current flows into the primary winding of T1 but the secondary diodes are not conducting and there is no secondary current. When Q1 turns " off " the primary current stops, all winding voltages reverse by flyback action, and the output diodes and secondary windings now conduct current.



Product Operation Mode

This highly integrated SCM1101A current mode PWM controller is designed for offline DC-DC converter applications. It's two key features are:

1. Under light load conditions, the IC will automatically reduce the PWM's switching frequency to achieve the highest possible efficiency. When the load is at or close to zero, the system enters into burst mode, thus reducing switching losses in standby operation.

2. Highly integrated protection features save the PCB area by reduced external component count and therefore improved system reliability. Condition: VDD=12V, RI=24kΩ, T=25[°]C (unless otherwise specified).

Extremely Low Start-up and Operating Current

The typical start-up current of SCM1101A is only about 1uA. This value refers to the chip's current consumption before the VDD voltage reaches the startup threshold voltage of 7.1V. Most of the startup circuit's current is used to charge the VDD capacitor, thus accelerating the start-up time of the chip.

The typical operating current of the SCM1101A part is as low as 1.4mA. The relatively small operating current results in higher efficiency and reduces the required VDD hold-up capacitance value.

Oscillator Frequency

To program the maximum switching frequency, a resistor between RI pin and GND with the following calculated value is being used:

$$F_{\max}(kHz) = \frac{7320}{RI(k\Omega)}$$

The recommended operating frequency range of the SCM1101A is between 200kHz and 500kHz (see also recommended operating parameters). If the resistor value connected to RI pin is too large (RI pin may become oversensitive) and the resulting operating frequency is too low. Also note that under extremely light load condition the minimum frequency can be less than 22kHz, resulting in the system generating some audible noise. If the operating frequency is too high, the power consumption of the chip will increase and the precision of frequency will decrease.

Externally Programmable Soft-start Function

This chip design allows the user for easy programming of the soft-start time Tss by means of connecting a capacitor between the SS pin and GND. The charge current ISS from the SS pin into the capacitor is calculated as follows:

$$I_{ss} = \frac{5}{8RI} \quad (2)$$

The correlation between the VSS voltage on the soft-start capacitor and the FB feedback voltage V_{FB} is:

If value of $V_{FB} \ge V_{SS}$, then V_{FB} is controlled by V_{SS} and V_{FB} signal is following V_{SS} ;

If value of $V_{FB} < V_{SS}$, then V_{FB} is no longer controlled by V_{SS} .

Describing a soft-start cycle: At the beginning of a converter start-up cycle, there is no current flow from the FB pin into the opto-coupler. The V_{FB} voltage follows the V_{SS} signal that rises as defined by C_{SS} . The duty cycle controlled by the PWM comparator will slowly increase going through the soft-start state. Under normal operation, the optocoupler starts pulling current from the FB port after the voltage feedback loop is established. As V_{FB} drops, V_{SS} signal will continue to climb with a fixed slope up to a maximum value, and the constant maximum value is maintained. This way V_{FB} becomes



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VER.A4 2020.04 Page 7 of 13

lower than V_{SS} , and will therefore not be controlled by V_{SS} . The peak current value is controlled by the voltage feedback loop, resulting in a smooth transition of the soft -start control into a feedback control loop operation. In other words, by the time the V_{SS} signal rise settles, the V_{FB} signal has also been established.

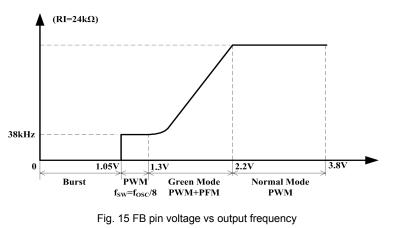
In addition, the chip features an integrated soft-start reset function and an SS pin suspending protection function.

Soft-start reset: If the chip's start-up or the self-recovery protection is revoked, the soft-start circuit enters a reset process by first resetting V_{SS} to ground potential, before resetting V_{FB} as well.

SS pin suspending protection: If the SS pin voltage V_{SS} raises after a soft-start reset up to 0.9V in 4us, the system recognizes the SS pin as suspended and will lock the GATE signal to low voltage level, indicating it has entered the SS pin suspending protection state. This protection prevents the device from being damaged by the large peak currents under following start-up conditions: The SS pin is open (not connected to soft-start capacitor, capacitor faulty) or the selected external capacitor value is too small.

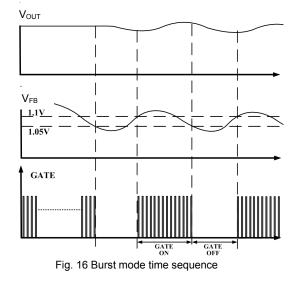
Smart Green Mode

The SCM1101A detects the FB port voltage V_{FB} for adjusting the oscillator frequency, which in turn adjusts the output GATE signal frequency. If 2.2V < V_{FB} < 3.8V, the system works in normal PWM mode; only the peak voltage of the CS pin is adjusted, the frequency maintains the maximum value. If 1.3V < V_{FB} < 2.2V, the system works in PWM+PFM mode; both the CS peak voltage and the systems operating frequency are regulated. The switching frequency gradually decreases with decreasing load, and if 1.05V < V_{FB} < 1.3V the system works in PWM mode and it has reached the minimum operating frequency which equals to 1/8 of the maximum operating frequency; when V_{FB} is less than 1.05V, the system enters into the energy saving burst mode with the GATE signal pulled low . How V_{FB} signal changes influences operating modes is shown in Fig. 15 below:



Burst Mode

In addition to the Smart Green Mode, a Burst Mode is also part of the SCM1101A design. If the V_{FB} signal decreases to 1.05V, the system enters Burst Mode, which is also known as frequency hopping mode. At this point, the PWM controller stops switching, the output voltage starts to drop according to the power consumption of the load, which causes the opto-coupler current to be reduced and the V_{FB} signal starts to rise again. As soon as the V_{FB} voltage rises above the threshold of 1.1V, the output driver resumes at the minimum switching frequency (i.e., 1/8 of the maximum frequency). In order to avoid any audible noise, the minimum switching frequency should be set higher than 22kHz. After the GATE output resumes to normal, the output voltage starts to rise again. Only when V_{FB} reverses below the 1.05V trigger point again, the system recycles and returns to the burst mode once again, as shown in Fig. 16.





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VER.A4 2020.04 Page 8 of 13

Feed-forward Compensation

By sampling the input voltage at the VIN pin, the feed forward resistor R_{LC} generates the compensation voltage V_{RLC} , which accomplishes the feed forward compensation and ensures a consistent over current point over the entire input voltage range. The R_{LC} feed forward resistor value can be calculated by the following formula:

$$R_{LC} = \frac{\left(R_{IN} + 45k\Omega\right) \times T_D}{5 \times L_P} \times R_{CS} \quad (3)$$

 T_{D} is the current detection delay time, including the MOSFET turn off delay.

 L_P is the primary side transformer inductance.

 R_{IN} , R_{CS} respectively represent the input resistance and the current sense resistance (see typical application).

Built-in Slope

The design consists of a two-stage compensation; when the duty is between 44% and 60%, the slope is 194.3mV/us and when the duty cycle is between 60% and 80%, the slope is 322.1mV/us. This two-stage design prevents the slope compensation from affecting the load carrying capacity. The above mentioned typical slope values are based on an external 24kΩ resistor connected to the RI pin.

Maximum Peak Current Limit

The SCM1101A limits the voltage of the CS pin to V_{CST_MAX} (see electrical characteristics), and the maximum peak current I_{PK_MAX} of the primary side inductance meets the following (slope compensation not taken into account):

$$I_{PK_MAX} = \frac{0.9 - V_{RLC}}{R_{CS}} \quad (4)$$

 V_{RLC} is the voltage on the feed forward resistance mentioned above, calculated as follows:

$$V_{RLC} = \frac{V_{IN} \times T_D}{L_P} \times R_{CS} \quad (5)$$

R_{CS} is the value of current sense resistance.

Limiting the maximum peak current will limit the maximum output current, calculated by the turns ratio. If the load current exceeds the maximum output current, the output voltage will drop sharply, the opto-coupler no longer pulls current from FB port, the V_{FB} value will rise until triggering the V_{FB} overvoltage protection (see below).

VIN Undervoltage Protection

VIN undervoltage protection point: V_{UVIN_OFF} can be set by the input resistor R_{IN}. The chip enters undervoltage protection state when the input voltage is lower than:

$$0.22 \times (R_{IN} + 45) / RI$$

The undervoltage protection is cancelled once the input voltage is greater than:

$$0.25 \times (R_{IN} + 45) / R_{IN}$$

resulting in a soft-start cycle being initiated. Note: Use resistor values for R_{IN} and RI in kilo-ohm (k Ω) for above formula.

V_{FB} Overvoltage Protection

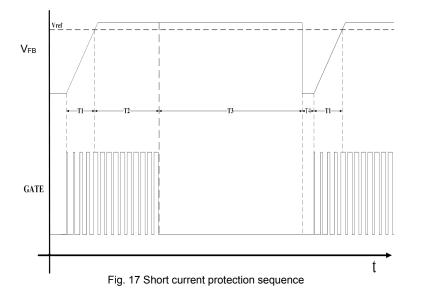
Once the accumulated time that the FB port voltage V_{FB} remains above 4.5V exceeds the delay time $T_{D_{-}PL}$ (see electrical characteristics, namely 10240 T_{OSC} , T_{OSC} is minimum switching period time), an overvoltage condition is detected. The chip forces the GATE to turn off immediately going into the V_{FB} overvoltage protection rest state. As long as V_{FB} stays below 4.5V before the elapsed time reaches the $T_{D_{-}PL}$, the V_{FB} overvoltage protection will not be triggered. T_{SLEEP} is the duration of the V_{FB} overvoltage protection rest state (see electrical characteristics, namely $2^{19}T_{OSC}$). After such a T_{SLEEP} cycle, the V_{FB} overvoltage protection is cancelled and the GATE signal is re-enabled, while soft-start is being reset pulling V_{FB} down. If the need for protection is no longer present at this time, the chip will run a soft-start cycle.

In similar fashion the V_{FB} overvoltage protection can be used to achieve over-power protection (OPP), output short-circuit protection (OSP) and open-loop protection (OLP), because all these conditions will result in V_{FB} rising to the point where it is exceeding the 4.5V threshold. The following Fig. 17 shows the sequence of the V_{FB} voltage and the GATE signal under the converters output short-circuit condition. T1 time period represents a soft-start cycle and the V_{FB} signal follows the soft-start capacitor voltage V_{SS} ; T2 represents the V_{FB} overvoltage protection delay time during which the GATE signal is still not forced to shut down; T3 represents the rest time of the V_{FB} overvoltage protection; at the end of the T3 phase the system cycles a soft-start reset process before soft-start can resume. If the output short-circuit of fault condition persists, the whole process above repeats itself.



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VER.A4 2020.04 Page 9 of 13



VDD Overvoltage Protection

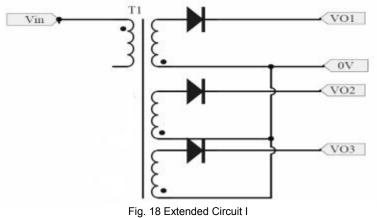
If the VDD port voltage exceeds 18V (VDD overvoltage protection point) for more than 200us, then the chip enters the VDD over-voltage protection state. The GATE signal stops and only after the VDD voltage decreases below the 14.8V threshold, the chip will cancel the VDD over-voltage protection signal, the soft-start resets, a soft-start cycle is initiated and the GATE signal returns to normal operation.

RI Pin Short-circuit Protection

During the protection detection time T_{RL_SHORT} (see electrical characteristics), any RI pin short-circuit condition is being detecting after the chip starts-up. If a short-circuit is detected, the GATE signal stops, the chip will remove the short-circuit protection mode and re-test the condition only when it re-starts again. If there is no short-circuit, it will recognize there is a normal connection on the RI pin, until the chip recycles, restarts and then retests.

Extended Output Design

SCM1101A chip is used to drive the push-pull circuit, which can make output voltage become higher.





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VER.A4 2020.04 Page 10 of 13 MORNSUN Guangzhou Science & Technology Co.,Ltd.reserves the copyright and right of finalinterpretation Vin: 9-36VDC Vo: 5VDC Io: 1.2A

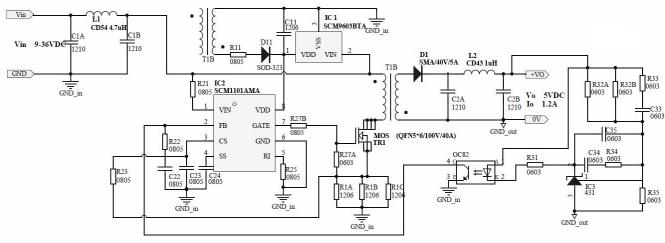


Fig. 19 Application Circuit I

Introduction of SCM9603BTA

The SCM9603B's built-in 85V high voltage transistor works over a wide input voltage range from 4VDC to 85VDC. A constant current output charges the bypass capacitor for starting-up the controller. After the controller start-up, the SCM9603B will continue to work for a certain period of time, which is beneficial to improve the capacitive ability of the power supply.

Please log in the official website of Mornsun (www.mornsun.cn) and contact the sales tobtain the datasheet.

Power Supply Recommendations

Unless otherwise specified, the following parameters are measured in the conditions of V_{VIN}= 5V.

- The rectified voltage of the AUX winding should not exceed 18V.
- VDD bias capacitor above 5uF . The greater power , the greater capacitance.
- The PCB routing to CS and FB pin should be as short and straight as possible.
- The layout of the IC should be away from the ESD test point.

Ordering Information

Part number	Package	Number of pins	Product Marking	Tape & Reel	Weight(1 PCS)	Weight (1 REEL include box)
SCM1101AMA	MSOP-8	8	1101A YM	4K/REEL	0.02g	805.2g

Product marking and date code

SCM1101XYZ:

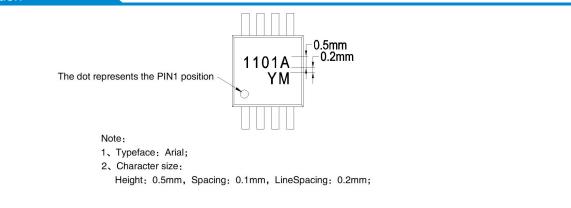
(1) SCM1101 = Product designation.

(2) X = Version code information (A-Z).

(3) Y = Packaging definition code; S for SOP package,

- (4) Z = Operating temperature range (C = 0 $^{\circ}$ C to +70 $^{\circ}$ C, I =-40 $^{\circ}$ C to +85 $^{\circ}$ C, A =-40 $^{\circ}$ C to +125 $^{\circ}$ C, M = -55 $^{\circ}$ C to +125 $^{\circ}$ C).
- (5) YM = Date code for product traceability; Y = code for production year; M = code for production month.

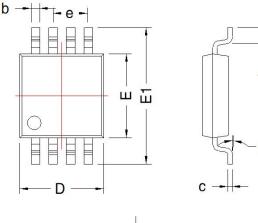
Silk Screen Information



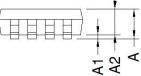


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THIRD ANGLE PROJECTION \bigoplus



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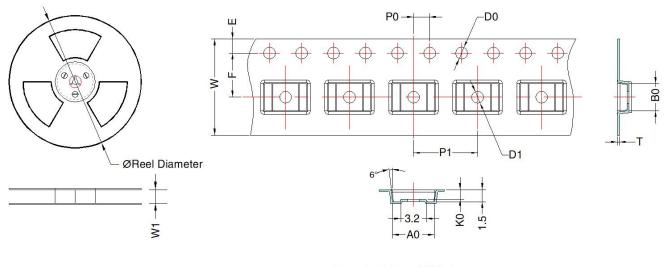


		MSOP-8		
Mark	Dimensi	on(mm)	Dimensio	on(inch)
Mark	Min	Max	Min	Max
Α	0.82	1.10	0.032	0.043
A1	0.02	0.15	0.001	0.006
A2	0.75	0.95	0.03	0.037
D	2.90	3.10	0.114	0.122
E	2.90	3.10	0.114	0.122
E1	4.75	5.05	0.187	0.199
L	0.40	0.80	0.016	0.031
b	0.25	0.38	0.010	0.015
e	0.65	ГҮР	0.026	TYP
С	0.09	0.23	0.004	0.009
θ	0°	6°	0°	6 °



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VER.A4 2020.04 Page 12 of 13 MORNSUN Guangzhou Science & Technology Co.,Ltd.reserves the copyright and right of finalinterpretation



The orientation of IC in tape

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Device	Package Type	MPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	T (mm)	W (mm)	E (mm)	F (mm)	P1 (mm)	P0 (mm)	D0 (mm)	D1 (mm)
SCM1101AMA	MSOP-8	4000	330.0	12.4	5.2 ± 0.1	3.3 ± 0.1	1.2 ± 0.1	0.25 ± 0.05	12.0 ± 0.3	1.75 ± 0.1	5.5 ± 0.1	8±0.1	4 ± 0.1	1.5 ± 0.1	1.5 ± 0.1

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